

# 74LVT14

## 3.3 V hex inverter Schmitt trigger

Rev. 02 — 25 April 2008

Product data sheet

### 1. General description

The 74LVT14 is a high-performance BiCMOS product designed for  $V_{CC}$  operation at 3.3 V. It is capable of transforming slowly changing input signals into sharply defined, jitter free output signals. In addition, it has a greater noise margin than conventional inverters.

Each circuit contains a Schmitt trigger followed by a Darlington level shifter and a phase splitter driving a TTL totem-pole output. The Schmitt trigger uses positive feedback to effectively speed-up slow input transitions, and provide different input threshold voltages for positive-going and negative-going inputs. The threshold differential (typically 600 mV) is determined internally by resistor ratios and is insensitive to temperature and supply voltage variations.

### 2. Features

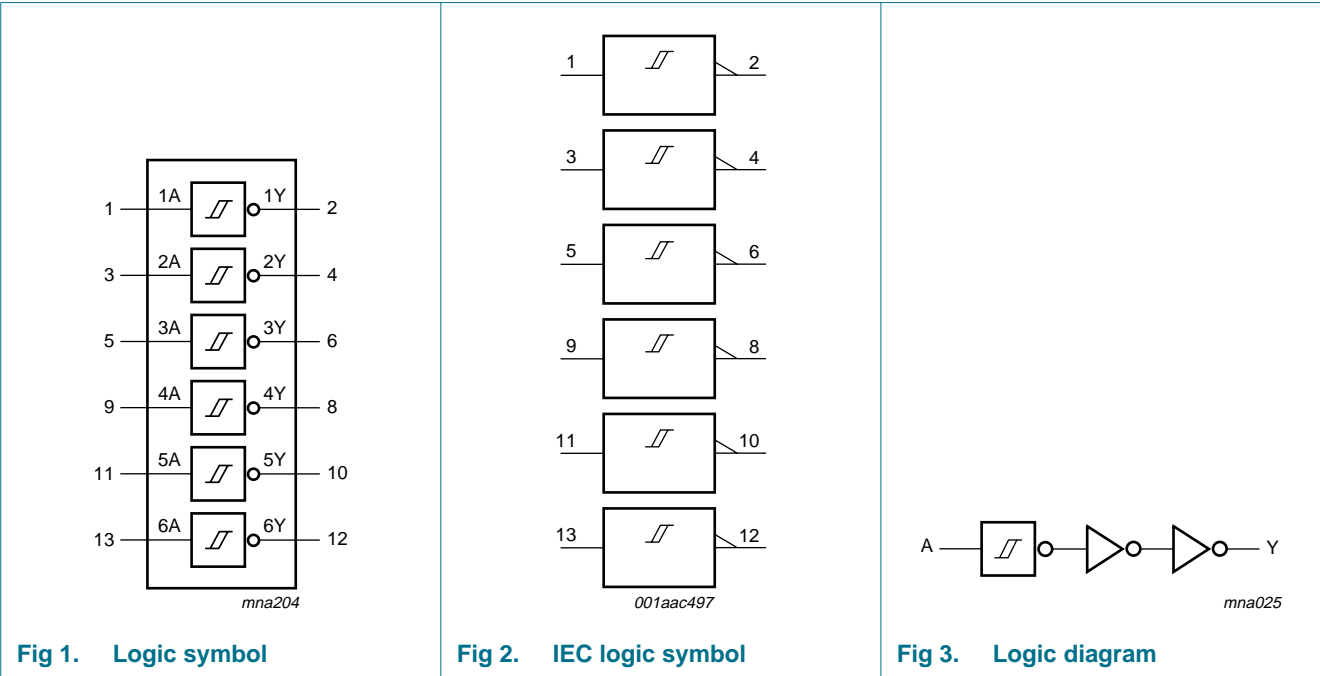
- Different positive and negative going input threshold voltages
- Tolerant of slow input transitions
- High noise immunity
- TTL input and output switching levels
- Output capability: +32 mA/–20 mA
- Latch-up protection exceeds 500 mA per JESD78 class II level A
- ESD protection:
  - ◆ HBM JESD22-A114E exceeds 2000 V
  - ◆ MM JESD22-A115-A exceeds 200 V

### 3. Ordering information

Table 1. Ordering information

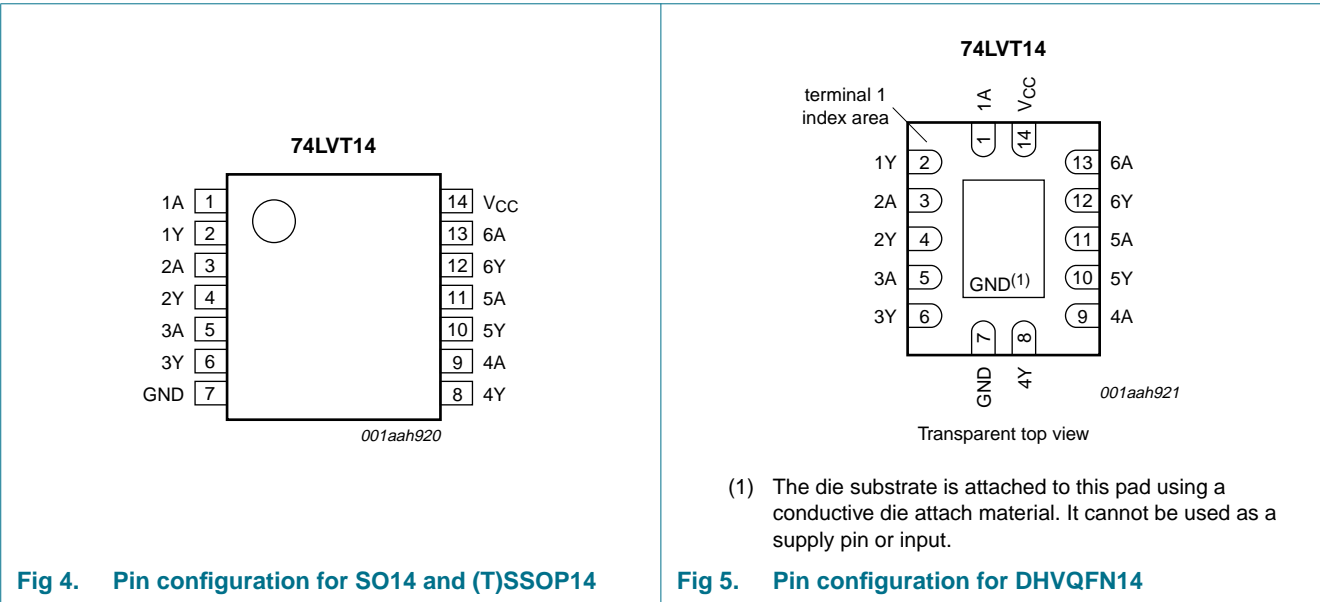
Type number	Package			
	Temperature range	Name	Description	Version
74LVT14D	–40 °C to +85 °C	SO14	plastic small outline package; 14 leads; body width 7.5 mm	SOT108-1
74LVT14DB	–40 °C to +85 °C	SSOP14	plastic shrink small outline package; 14 leads; body width 5.3 mm	SOT337-1
74LVT14PW	–40 °C to +85 °C	TSSOP14	plastic thin shrink small outline package; 14 leads; body width 4.4 mm	SOT402-1
74LVT14BQ	–40 °C to +85 °C	DHVQFN14	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 × 4.5 × 0.85 mm	SOT762-1

4. Functional diagram



5. Pinning information

5.1 Pinning



## 5.2 Pin description

**Table 2.** Pin description

Symbol	Pin	Description
1A to 6A	1, 3, 5, 9, 11, 13	data input
1Y to 6Y	2, 4, 6, 8, 10, 12	data output
GND	7	ground (0 V)
V <sub>CC</sub>	14	positive supply voltage

## 6. Functional description

**Table 3.** Function selection

Inputs	Output
nA	nY
L	H
H	L

- [1] H = HIGH voltage level;  
L = LOW voltage level.

## 7. Limiting values

**Table 4.** Limiting values [1]

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+4.6	V
V <sub>I</sub>	input voltage		[2] -0.5	+7.0	V
V <sub>O</sub>	output voltage	output in OFF or HIGH state	[2] -0.5	+7.0	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V	-50	-	mA
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V	-50	-	mA
I <sub>O</sub>	output current	output in LOW state	-	64	mA
		output in HIGH state	-32	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
T <sub>j</sub>	junction temperature			+150	°C
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = -40 °C to +85 °C	[3]	500	mW

- [1] The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150 °C.
- [2] The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.
- [3] For SO14 packages: above 70 °C derate linearly with 8 mW/K.  
For SSOP14 and TSSOP14 packages: above 60 °C derate linearly with 5.5 mW/K.  
For DHVQFN14 packages: above 60 °C derate linearly with 4.5 mW/K.

## 8. Recommended operating conditions

**Table 5. Recommended operating conditions**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{CC}$	supply voltage		2.7	-	3.6	V
$V_I$	input voltage		0	-	5.5	V
$I_{OH}$	HIGH-level output current		-20	-	-	mA
$I_{OL}$	LOW-level output current		-	-	32	mA
$T_{amb}$	ambient temperature	in free air	-40	-	+85	°C
$\Delta t/\Delta V$	input transition rise and fall rate	output enabled	0	-	10	ns/V

## 9. Static characteristics

**Table 6. Static characteristics**

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40 °C to +85 °C			Unit
			Min	Typ <sup>[1]</sup>	Max	
$V_{T+}$	positive-going threshold voltage	$V_{CC} = 3.3\text{ V}$ ; see <a href="#">Figure 7</a>	1.5	1.7	2.0	V
$V_{T-}$	negative-going threshold voltage	$V_{CC} = 3.3\text{ V}$ ; see <a href="#">Figure 7</a>	0.9	1.1	1.3	V
$V_H$	hysteresis voltage	$V_{CC} = 3.3\text{ V}$ ; see <a href="#">Figure 7</a>	0.4	0.6	-	V
$V_{IK}$	input clamping voltage	$V_{CC} = 2.7\text{ V}$ ; $I_{IK} = -18\text{ mA}$	-1.2	-	-	V
$V_{IH}$	HIGH-level input voltage		2.0	-	-	V
$V_{IL}$	LOW-level input voltage		-	-	0.8	V
$V_{OH}$	HIGH-level output voltage	$V_{CC} = 2.7\text{ V to }3.6\text{ V}$ ; $I_{OH} = -100\text{ }\mu\text{A}$	$V_{CC} - 0.2$	-	-	V
		$V_{CC} = 2.7\text{ V}$ ; $I_{OH} = -6\text{ mA}$	2.4	-	-	V
		$V_{CC} = 3.0\text{ V}$ ; $I_{OH} = -20\text{ mA}$	2.0	-	-	V
$V_{OL}$	LOW-level output voltage	$V_{CC} = 2.7\text{ V}$ ; $I_{OL} = 100\text{ }\mu\text{A}$	-	-	0.2	V
		$V_{CC} = 2.7\text{ V}$ ; $I_{OL} = 24\text{ mA}$	-	-	0.5	V
		$V_{CC} = 3.0\text{ V}$ ; $I_{OL} = 32\text{ mA}$	-	-	0.5	V
$I_I$	input leakage current	$V_{CC} = 0\text{ V or }3.6\text{ V}$ ; $V_I = 5.5\text{ V}$	-	-	10	$\mu\text{A}$
		$V_{CC} = 3.6\text{ V}$ ; $V_I = V_{CC}\text{ or GND}$	-	-	$\pm 1$	$\mu\text{A}$
$I_{OFF}$	power-off leakage current	$V_{CC} = 0\text{ V}$ ; $V_I\text{ or }V_O = 0\text{ V to }4.5\text{ V}$	-	-	$\pm 100$	$\mu\text{A}$
$I_{CC}$	supply current	$V_{CC} = 3.6\text{ V}$ ; $V_I = \text{GND or }V_{CC}$ ; $I_O = 0\text{ A}$				
		outputs HIGH	-	-	0.02	mA
		outputs LOW	-	1.5	3	mA
$\Delta I_{CC}$	additional supply current	per input pin; $V_{CC} = 3.0\text{ V to }3.6\text{ V}$ ; one input = $V_{CC} - 0.6\text{ V}$ ; other inputs at $V_{CC}\text{ or GND}$	<sup>[2]</sup> -	-	0.2	mA
$C_I$	input capacitance	$V_I = 0\text{ V or }3.0\text{ V}$	-	3	-	pF

[1] All typical values are measured at  $V_{CC} = 3.3\text{ V}$  (unless stated otherwise) and  $T_{amb} = 25\text{ }^\circ\text{C}$ .

[2] This is the increase in the supply current for each input at the specified voltage level other than  $V_{CC}\text{ or GND}$ .

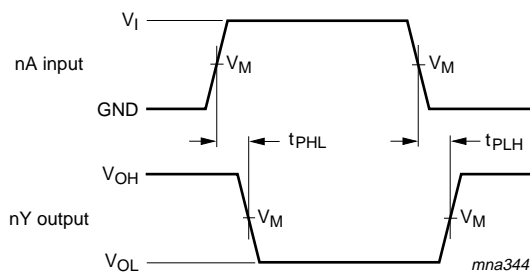
10. Dynamic characteristics

Table 7. Dynamic characteristics  
Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 8.

Symbol	Parameter	Conditions	-40 °C to +85 °C			Unit
			Min	Typ <sup>[1]</sup>	Max	
t <sub>PLH</sub>	LOW to HIGH propagation delay	nA to nY				
		V <sub>CC</sub> = 2.7 V	-	-	6.9	ns
		V <sub>CC</sub> = 3.3 V + 0.3 V	1.0	3.8	5.7	ns
t <sub>PHL</sub>	HIGH to LOW propagation delay	nA to nY				
		V <sub>CC</sub> = 2.7 V	-	-	4.1	ns
		V <sub>CC</sub> = 3.3 V + 0.3 V	1.0	3.2	4.5	ns

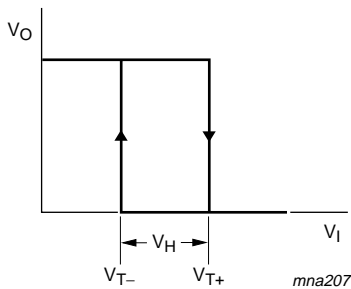
[1] Typical values are measured at T<sub>amb</sub> = 25 °C and V<sub>CC</sub> = 3.3 V.

11. Waveforms

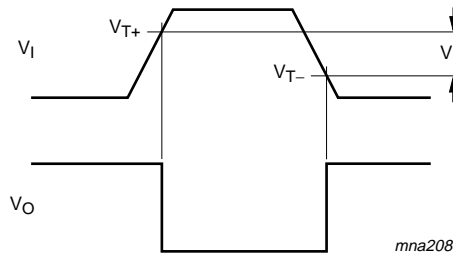


See Table 8 for measurement points.  
V<sub>OL</sub> and V<sub>OH</sub> are typical output voltage levels that occur with the output load.

Fig 6. nA Input to nY output propagation delays



a. Transfer characteristics

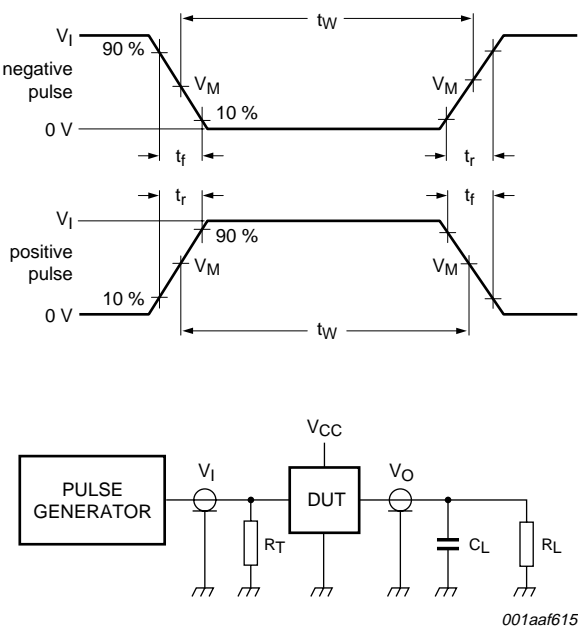


b. Voltage levels

Fig 7. Definition of V<sub>T+</sub>, V<sub>T-</sub> and V<sub>H</sub>

Table 8. Measurement points

V <sub>CC</sub>	Input	Output
	V <sub>M</sub>	V <sub>M</sub>
2.7 V to 3.6 V	1.5 V	1.5 V



Test data is given in given in [Table 9](#).  
Definitions for test circuit:  
 $R_L$  = Load resistance;  
 $C_L$  = Load capacitance including jig and probe capacitance;  
 $R_T$  = Termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.

Fig 8. Load circuitry for switching times

Table 9. Test data

Supply	Input pulse requirements					Load	
V <sub>CC</sub>	V <sub>I</sub>	Repetition rate	t <sub>W</sub>	t <sub>r</sub> , t <sub>f</sub>		R <sub>L</sub>	C <sub>L</sub>
2.7 V to 3.3 V	2.7 V	≤ 10 MHz	500 ns	≤ 2.5 ns		500 Ω	50 pF

12. Package outline

SO14: plastic small outline package; 14 leads; body width 3.9 mm SOT108-1

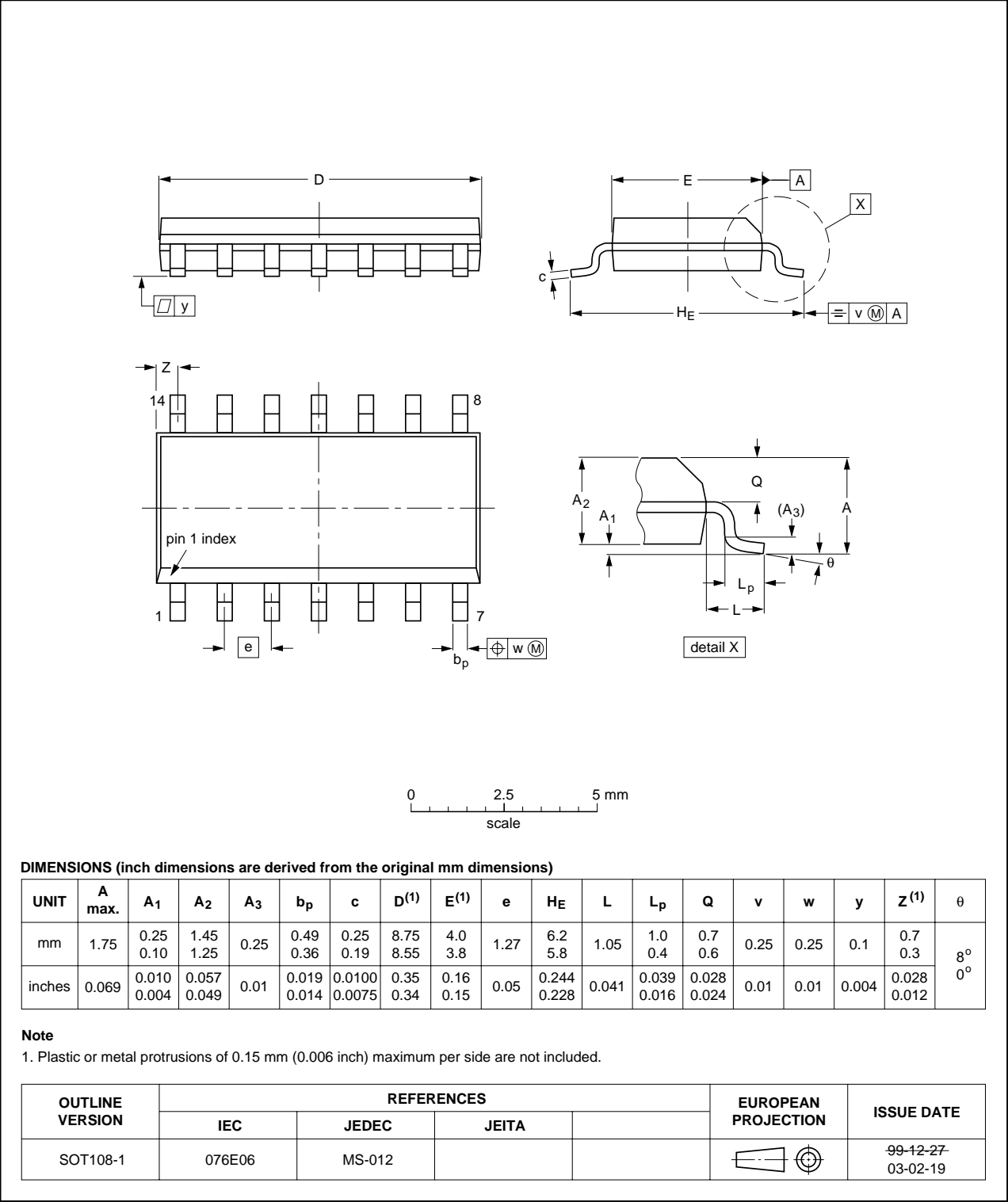


Fig 9. Package outline SOT108-1 (SO14)

SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1

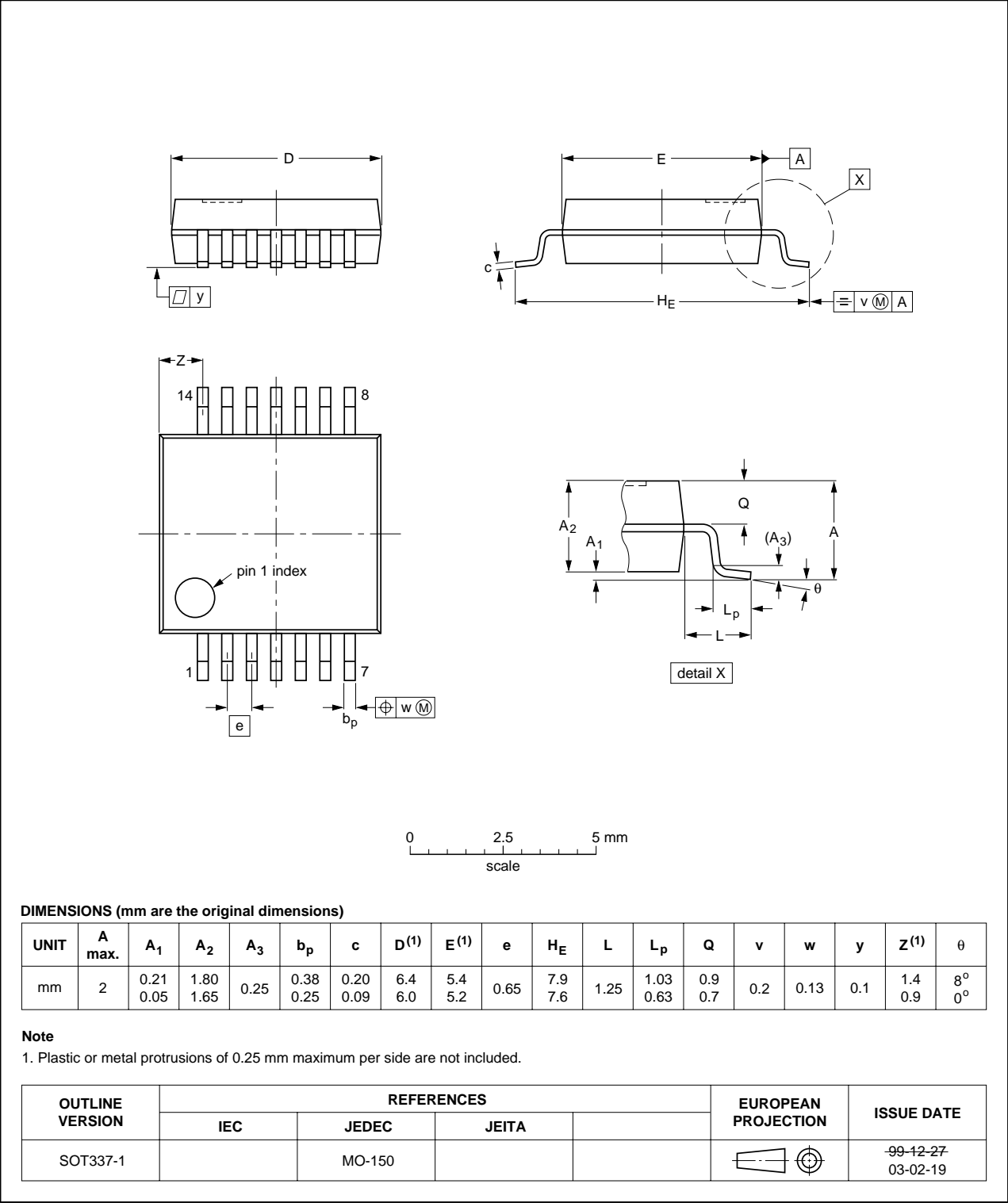


Fig 10. Package outline SOT337-1 (SSOP14)



TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1

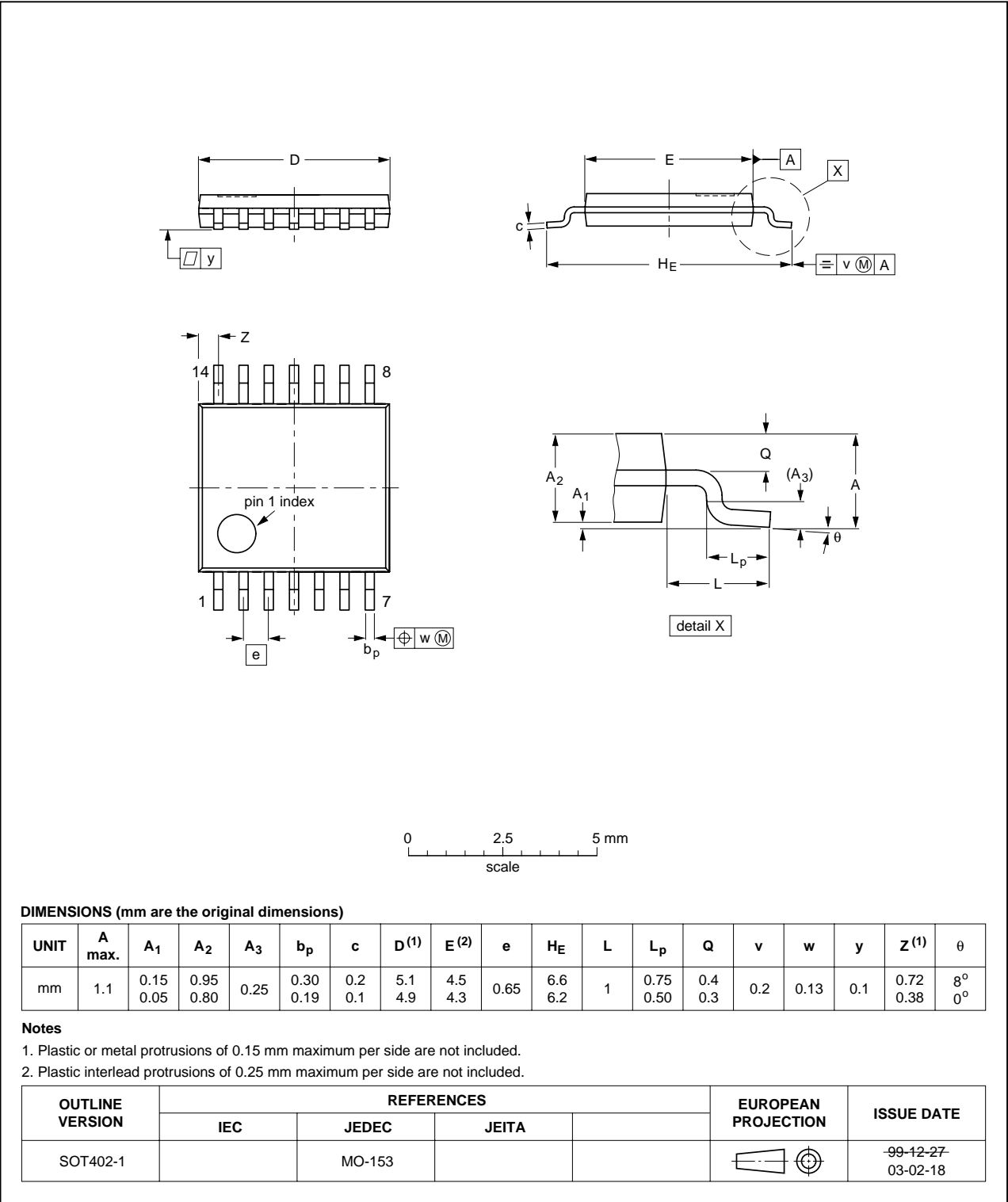


Fig 11. Package outline SOT402-1 (TSSOP14)

DHVQFN14: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 x 3 x 0.85 mm

SOT762-1

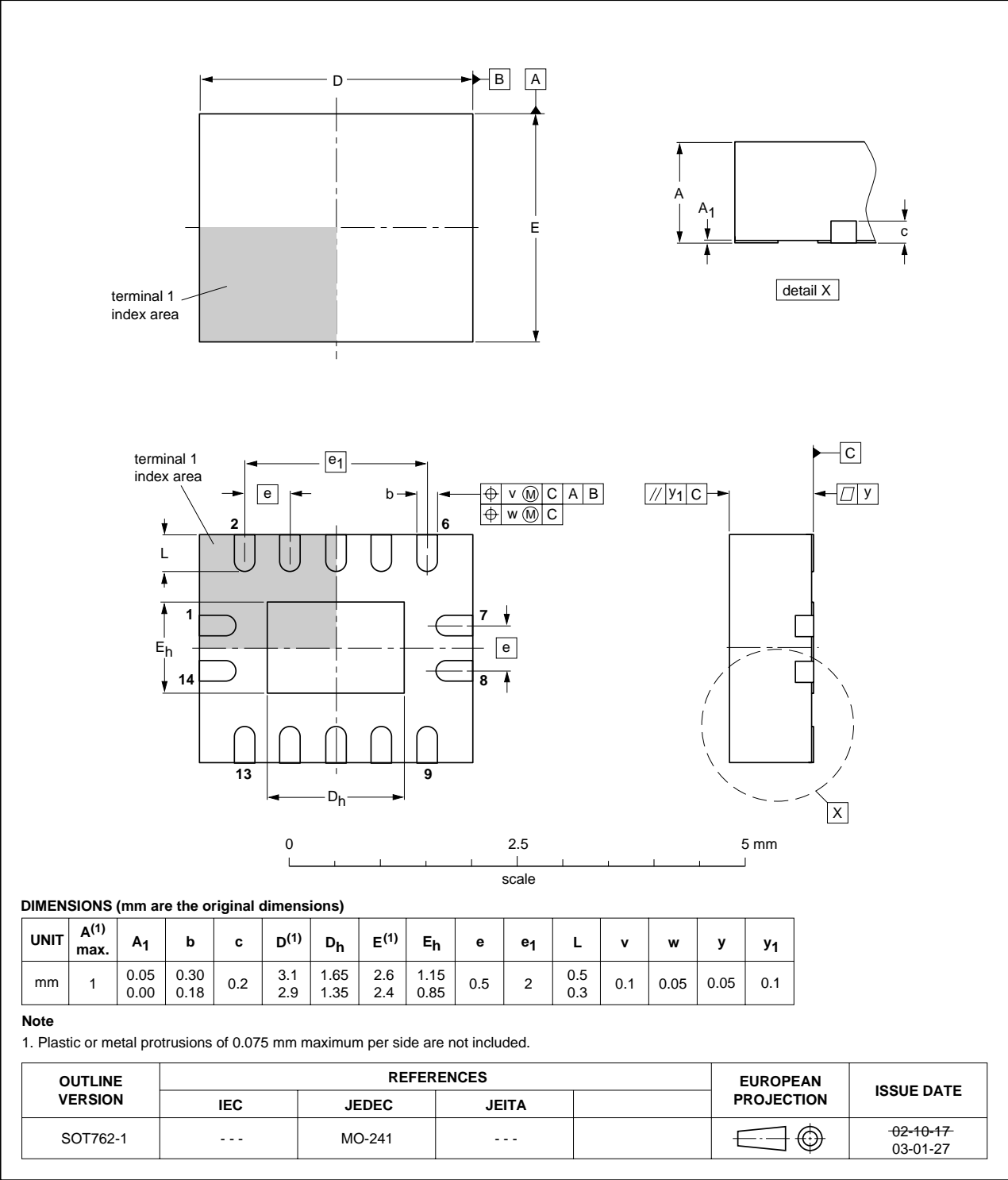


Fig 12. Package outline SOT762-1 (DHVQFN14)

## 13. Abbreviations

Table 10. Abbreviations

Acronym	Description
BiCMOS	Integrated Bipolar junction transistors and CMOS
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
TTL	Transistor-Transistor Logic

## 14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVT14_2	20080425	Product data sheet	-	74LVT14_1
Modifications:	<ul style="list-style-type: none"><li>• The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li><li>• Legal texts have been adapted to the new company name where appropriate.</li><li>• Quick reference section removed.</li><li>• DHVQFN14 package added to <a href="#">Section 3 “Ordering information”</a> and <a href="#">Section 12 “Package outline”</a>.</li><li>• <a href="#">Section 13 “Abbreviations”</a> added.</li></ul>			
74LVT14_1	19960828	Product specification	-	-

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Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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